

MONOLITHIC MICROCHIP CAPACITOR BONDING TYPE FOR GENERAL GMA0D3R71A103MA01_ (015015, X7R, 10000pF, 10Vdc)

_: packaging code Reference Sheet

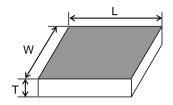
1.Scope

This product specification is applied to Monolithic Microchip Capacitor Bonding Type used for General Electronic equipment for wire-bonding / die-bonding..

2.MURATA Part NO. System

(Ex.)	GMA	0D	3	R7	1A	103	М	A01	Т
		(1)L/W Dimensions	(2)T Dimensions	(3)Temperature Characteristics	(4)DC Rated Voltage	(5)Nominal Capacitance	(6)Capacitance Tolerance	(7)Murata's Control Code	(8)Packaging Code

3. Type & Dimensions



		m	

(1)-1 L	(1)-2 W	(2) T
0.38±0.05	0.38±0.05	0.3±0.05

4.Rated value

(/	(3) Temperature Characteristics (Public STD Code):X7R(EIA)			(6) Capacitance	Specifications and Test Methods	
Temp. coeff or Cap. Change	Temp. Range (Ref.Temp.)	DC Rated Voltage	Capacitance	Tolerance	(Operationg Temp. Range)	
-15 to 15 %	-55 to 125 °C (25 °C)	10 Vdc	10000 pF	±20 %	-55 to 125 °C	

5.Package

mark	(8) Packaging	Packaging Unit
Т	Bulk Tray	400 pcs./Tray

Product specifications in this catalog are as of Oct.22,2012,and are subject to change or obsolescence without notice. Please consult the approval sheet before ordering.

Please read rating and !Cautions first.

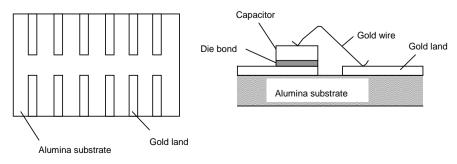
■ SPECIFICATIONS AND TEST METHODS

N1.		ha.ma	Charification	1			Took Matter d			
No		tem	Specification		Test Method Reference Temperature : 20°C(R7:25°C)					
1	Operating	5	B1, B3 : -25°C to +85°C R1, R7 : -55°C to +125°C		Reference Temperature : 20°C(R7:25°C)					
	Temperature	Range								
_										
2	Rated Voltag	Voltage See the previous pages.			The rated voltage is defined as the maximum voltage which may					
							sly to the capacitor.			
				When	AC۱	oltage is s	superimposed on DC voltage	, V ^{P-P} or V ^{O-P} ,		
				which	ever	is larger, s	hould be maintained within th	ne rated voltage		
	A = = = = = = = = = = = = = = = = = = =									
٥	Appearance		no defects of abhormalities.	Visual	Visual inspection.					
4	Dimension		Within the specified dimensions.	Lleing	Llein et polin etc					
4	Difficusion		Within the specified differsions.	Using	Using calipers.					
-	Dielectric Stre	anath	No defects or abnormalities.	No fai	No failure should be observed when 250% of the rated voltage					
٦	Dielectric Stre	angui	ino delects of abilitimalities.					•		
							e terminations for 1 to 5 seco			
				provid	iea tr	ie cnarge/c	discharge current is less than	50mA.		
_	la a datia a		0 < 0.047 F . Marra th are 40000M0	Th - 1:-			and the state of t	h - DO!t		
6	Insulation		C≦0.047µ F : More than 10000MΩ				nce should be measured with	•		
	Resistand	ce	C>0.047μ F : More than 500Ω • F			-	ed voltage at 20°C/25°C and			
			C: Nominal Capacitance	and w	ithin	2 minutes	of charging, provided the cha	arge/discharge		
				current is less than 50mA.		DmA.				
$ldsymbol{le}}}}}}$										
7	Capacitance		Within the specified tolerance.		•		should be measured at 20°C	C/25°C at the		
L				freque	ency a	and voltage	e shown in the table.			
8	Dissipation F	actor	B1,B3,R1,R7							
	(D.F.)		W.V.: 25Vmin: 0.025 max.		Fr	equency	1±0.1kHz			
	,		W.V.: 16/10V: 0.035 max.		\ \	/oltage	1±0.2Vrms			
			W.V. : 6.3V : 0.05 max.							
			W.V 0.3V . 0.03 Max.							
9	Capacitance	No bias	B1, B3 : Within ±10%	The ca	apaci	tance char	nge sholud be measured afte	er 5 min. at		
	Temperature	50% of the	(-25 to +85°C)	each s	each specified temp. stage.					
	Characteristics		R1,R7 : Within ±15%	The ra	anges	of capacit	tance change compared with	Reference		
			(-55 to +125°C)		_		ver the temperature ranges s			
			(55 to 1 125 5)	-			ithin the specified ranges. *			
				lile tai	DIE SI	iouia be w	ithin the specified ranges.	-		
					St	tep		Temperature(°C)	Applying	
			B1 : Within +10/-30%		<u> </u>		20.0/25.0	Voltge(V)		
		Rated Voltage	R1 : Within +15/-40%		1		20±2/25±2			
					2	-55±3(fc	or R1, R7) / -25±3(for B1, B3)	No bias		
					3		20±2/25±2	INO bias		
					4	125+3(f	or R1, R7) / 85±3(for B1, B3)			
					5	120_0(
				l 			20±2/25±2	4		
					6	-55±	±3(for R1) / -25±3(for B1)	50% of the rated		
					7		20±2	voltage		
				8	8	125	±3(for R1) / 85±3(for B1)	1		
1	1]		<u> </u>						
	1			* Initia	al me	asurement	for high dielectric constant ty	ype		
				Perfor	rm a l	heat treatm	nent at 150 +0/-10°C for one	hour and then set		
1	1			for 24	±2h	ours at roo	om temperature.			
1	1			Perfor	rm the	e initial me	asurement.			
 			D. II.C							
10	Mechanical	Bond	Pull force : 0.03N min.	_			2011 Conition D			
1	Strength	Strength				-	on a gold metallized alumina			
]		Au-Sn	1(80/2	20) and bor	nd a 25µ m(0.001 inch) gold	wire to the		
1	1]		capac	itor te	erminal usi	ng an ultrasonic ball bond. T	hen, pull wire.		
1	1									
		Die Shear	Die Shear force : 2N min.	MIL-S	TD-8	83 Method	1 2019			
	1	Strength		Mount	t the	capacitor o	on a gold matallized alumina	substrate with		
	1	J				•	the force parallel to the subst			
l				, 011	. (00/2	/	3.00 paramor to the subst			
11	Vibration	Appearance	No defects or abnormalities.	Ramp	frea	uency from	10 to 55Hz then return to 10	Hz all within 1		
١.,	Resistance		25.55.5 5. aprioringingo.				5 mm(0.06 inch) max. total e			
1	1 TOSISIAI IUU	Capacitanas	Within the enecified telerance							
1	1	Capacitance	Within the specified tolerance.		Apply thie motion for a period of 2 hours in each of 3 muturally					
1				perpe	ndicu	ııar directio	ons (total 6 hours).			
l	1	D.F.	B1,B3,R1,R7							
1]	W.V.: 25Vmin: 0.025 max.							
1	1]	W.V.: 16/10V: 0.035 max.							
1	1		W.V.: 6.3V: 0.05 max.							
]								
•	•		•							

■SPECIFICATIONS AND TEST METHODS

No	lo Item		Specification	Test Method						
12	Temperature Cycle		The measured and observed characteristics should	The capacitor should be set for 24±2 hours at room temperature after one hour heat of treatment at 150 +0/-10 °C, then						
			satisfy the specifications in the following table.							
		Appearance	No defects or abnormalities.	Perform the five cycles according to the four heat tr			four heat treatments			
		l ''				,				
		Capacitance	B1, B3, R1, R7 : Within ±7.5%	-	measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same					
		Change				as (11) and conduct the five				
		onango								
		D.F.	B1,B3,R1,R7		temperatures and time shown in the following table. Set for 24±2					
		D.1 .	W.V. : 25Vmin: 0.025 max.	hours at room temperature, then measure.						
			W.V.: 16/10V: 0.035 max.		Step	Temp.(°C)	Time (min.)			
			W.V.: 6.3V: 0.05 max.		1	Min.	30±3			
			W.V.: 6.3V: 0.05 max.	-		Operating Temp.+0/-3				
		I.R.	More than 10,000MΩ or 500Ω ∙F	1 L	2	Room Temp	2 to 3			
		I.K.	· ·		3	Max. Operating Temp.+3/-0	30±3			
		Dialastria	(Whichever is smaller)	4 f	4	Room Temp	2 to 3			
		Dielectric	No defects.	l L		Room temp	2 10 3			
L		Strength								
13	Humidity		The measured and observed characteristics should	Set t	he cap	acitor at 40±2°C and 90 to 95	5% humidity			
	(Steady Sta	ate)	satisfy the specifications in the following table.	for 5	00±12	hours.				
		Appearance	No defects or abnormalities.	Rem	ove ar	d set for 24±2 hours at room	temperature,			
				then	then measure.					
		Capacitance	B1, B3, R1, R7 : Within ±12.5%							
		Change	_ , _ , , , , , , , , , , , , , , , , ,							
		D.F.	B1,B3,R1,R7	-						
		D.1 .	W.V. : 10Vmin: 0.05 max.							
			W.V. : 6.3V : 0.075 max.							
				4						
		I.R.	More than 1,000M Ω or 50 Ω •F							
			(Whichever is smaller)							
14	Humidity		The measured and observed characteristics should	Appl	y the ra	ated voltage at 40±2°C and 9	0 to 95% humidity			
			satisfy the specifications in the following table.	for 5	00±12	hours.				
		Appearance	No defects or abnormalities.	Rem	ove ar	d set for 24±2 hours at room	temprature, then			
		1				he charge/discharge current	-			
		Capacitance	B1, B3, R1, R7 : Within ±12.5%	1		0 0				
		Change	21, 26, 111, 111 11111111 = 121676							
		D.F.	D1 D2 D1 D7	-						
		D.1 .	B1,B3,R1,R7							
			W.V.: 10Vmin: 0.05 max.							
			W.V. : 6.3V : 0.075 max.							
				4						
		I.R.	More than 500MΩ or $25\Omega \cdot F$							
			(Whichever is smaller)							
15	High Temp	erature	The measured and observed characteristics should	Appl	y 200%	of the rated voltage at the r	naximun operating			
	Load		satisfy the specifications in the following table.	temp	eratur	e±3°C for 1000±12 hours.				
		Appearance	No defects or abnormalities.	Set f	or 24±	2 hours at room temperature	, then measure.			
						/discharge current is less that				
		Capacitance	B1, B3, R1, R7 : Within ±12.5%	1	0	<u> </u>				
		Change	, , , ,	• Initi	al mea	surement				
		D.F.	B1 B3 D1 D7	-		% of the rated DC voltage at	the maximum operating			
		D.1 .	B1,B3,R1,R7		-	-	· -			
			W.V.: 10Vmin: 0.05 max.		•	e ±3°C for one hour. Remov	e and Set IOI			
			W.V. : 6.3V : 0.075 max.	24±	∠ nours	s at room temperature.				
				4						
		I.R.	More than 1,000MΩ or 50Ω • F	1						
		1.13.	10010 (11011 1,00010122 01 0022 1							

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding and wire bonding when tests No.11 to 15 are performed.



Limitation of use

Please contact our sales representatives or product engineers before using our products for the applications listed below which require of our products for other applications than specified in this product.

- ①Aircraft equipment ②Aerospace equipment ③Undersea equipment ④Power plant control equipment
- ⑤Medical equipment ⑥Transportation equipment(vehicles,trains,ships,etc.) ⑦Traffic signal equipme
- ®Disaster prevention / crime prevention equipment
 9Data-processing equipment
- (1)Application of similar complexity and/or requirements to the applications listed in the above

Strage and Operation conditions

Note the following to prevent quality degradation.

- ①Store the capacitors in an environment whose temperature and relative humidity range from 5 to 40°C and 20 to 70%RH respectively and away from direct sunlight and shock. Please use product within six months of receipt.
- 2) Avoid storing the capacitors in an atmosphere containing corrosive gases (CI₂, H₂S, SO₂, NO_x, etc.).
- 3Do not directly touch capacitors with hands.

Die Bonding of capacitors

Use the following materials

Braze alloy:

Au-Sn (80/20) 300 to 320°C in N2 atmosphere

- Mounting
- (1)Control the temperature of the substrate so that it mathes the temperature of the braze alloy.
- ②Place braze alloy on substrate and place the capacitor on the alloy. Hold the capacitor and gently apply the load. Be sure to complete the operation in 1 minute.

■ Wire Bonding

Wire

Gold wire: 25µ m (0.001 inch) diameter

- Bondina
- 1)Thermocompression, ultrasonic ball bonding.
- ②Required stage temperature: 150 to 200°C.
- 2 Required wedge of capillary weight: 0.2N to 0.5N.
- 3)Bond the capacitor and base substrate or other devices with gold wire.

Others

(1) Resin Coating

When selecting resin materials, select those with low contraction.

(2) Circuit Design

GMA Series capacitors in this catalog are not safety recognized products.

Remarks

The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.

Select optimum conditions for operation as they determine the reliability of the product after assembly.

NOTE

- 1.Please make sure that your product has been evaluated in view of your specifications with our product being mounted to your product.
- 2. Your are requested not to use our product deviating from this product specification.
- 3.We consider it not appropriate to include any terms and conditions with regard to the business transaction in the product specifications, drawings or other technical documents. Therefore, if your technical documents as above include such terms and conditions such as warranty clause, product liability clause, or intellectual property infringement liability clause, they will be deemed to be invalid.